NSN 5961-01-119-4178



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-119-4178 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.352 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to emitter voltage/static/base open and 120.0 collector to base voltage, dc and 4.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 150.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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